

Robust Quantum-Based Interatomic Potentials for Transition Metals



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Outline



- **Quantum-based interatomic potentials**
 - linking first-principles quantum mechanics to large-scale atomistic simulation via GPT method
 - simplified *model* GPT or MGPT for central transition metals
- **Selected MGPT applications in Ta, Mo and V prototypes**
 - high-pressure phase transitions
 - multiphase equation of state, melt and polymorphism
 - dislocations and multiscale modeling of yield strength
- **Beyond the standard theory: advanced MGPT capabilities**
 - matrix MGPT: *f*-electrons, non-canonical bands, fast algorithms
 - *sp-d* hybridization: series-end transition metals, e.g., Ni
 - inclusion of electron temperature: T-dependent potentials

Bridging the gap from quantum mechanics to large-scale atomistic simulation



Material-dependent gap

Electronic: electron + ion motion

Atomic: ion motion only

Many-electron states

.....

Self-consistent mean field

Coarse-grained electronic structure

.....

No electronic structure

Correlated electron theory

Density Functional Theory (DFT)

Quantum based potentials

Empirical potentials

Exact quantum mechanics

Total empirical description

“ab initio”

“empirical”

QMC
DMFT
...

QMD
PP
FP-LMTO
...

GPT
MGPT
BOP
...

EAM
FS
...

Quantum simulation

Atomistic simulation

with BG/L

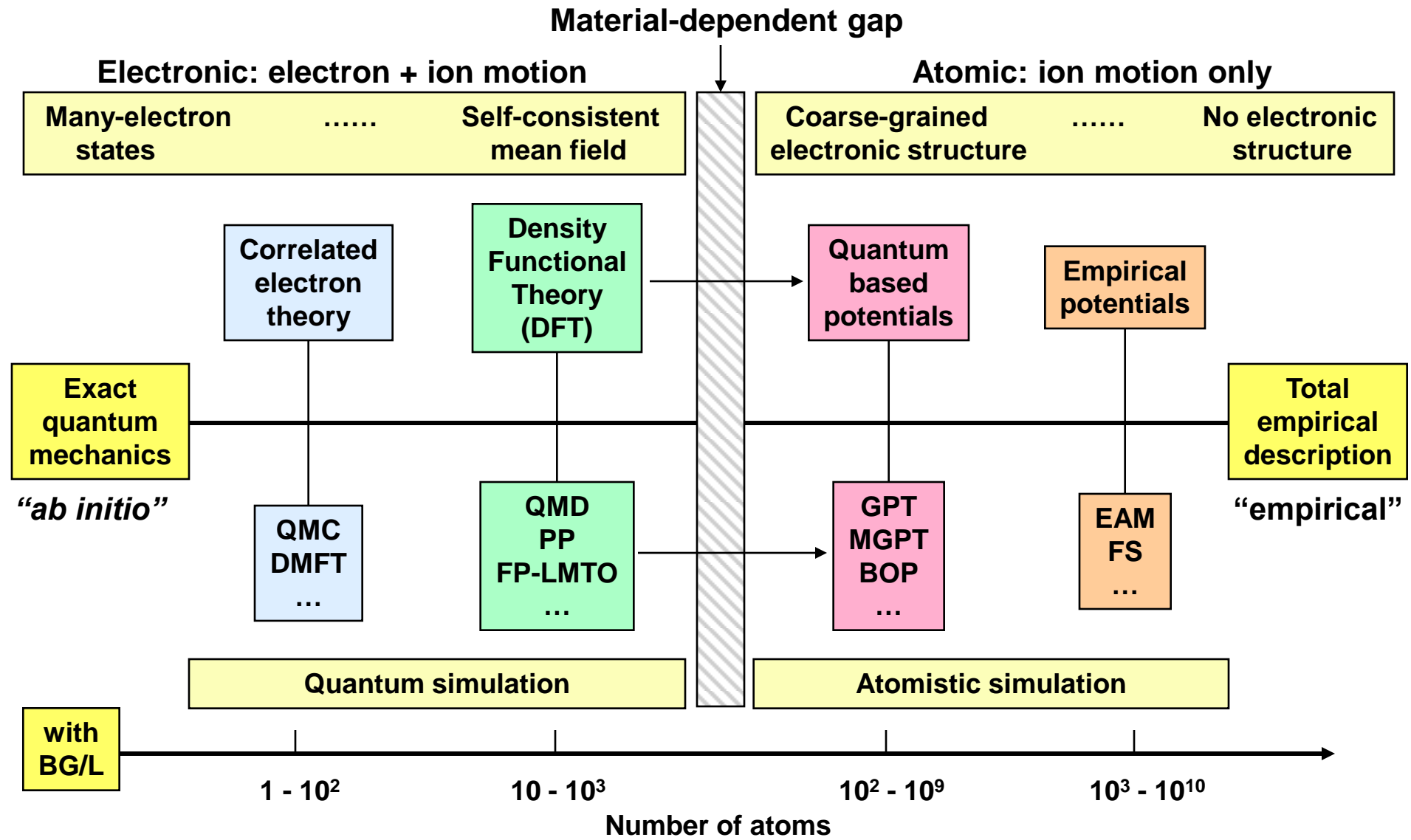
$1 - 10^2$

$10 - 10^3$

$10^2 - 10^9$

$10^3 - 10^{10}$

Number of atoms



Generalized Pseudopotential Theory (GPT)



- **Mixed basis:** $|\vec{k}\rangle, |\phi_d\rangle$ (DFT quantum mechanics)

- expansions in weak matrix elements

sp pseudopotential: $\langle \vec{k} + \vec{q} | w | \vec{k} \rangle$

d-d tight-binding: $\langle \phi_d^i | \Delta | \phi_{d'}^j \rangle$ & $\langle \phi_d^i | \phi_{d'}^j \rangle$

- self-consistent screening

sp-d hybridization: $\langle \vec{k} | \Delta | \phi_d \rangle$ & $\langle \vec{k} | \phi_d \rangle$

- **Total-energy functional:** (bulk formulation: atomic volume Ω)

$$E_{tot}(R_1, \dots, R_N) = NE_{vol}(\Omega) + \frac{1}{2} \sum_{i,j} v_2(ij; \Omega) + \frac{1}{6} \sum_{i,j,k} v_3(ijk; \Omega) + \frac{1}{24} \sum_{i,j,k,l} v_4(ijkl; \Omega)$$

volume

radial forces

angular forces

- structure-independent potentials: *rigorous transferability*
- atomistic simulation: MS, MD, MC

ab initio GPT: simple & series-end transition metals: Mg, Cu, ...
binary and ternary alloys: $\text{TM}_x\text{Al}_{1-x}$...

GPT

model GPT: central transition metals: Mo, Ta, ...
canonical *d* bands; analytic v_3 and v_4

MGPT

Simplified MGPT for central d -transition metals



$$E_{tot}(R_1, \dots, R_N) = \underline{NE_{vol}(\Omega)} + \frac{1}{2} \sum_{i,j} v_2(ij; \Omega) + \frac{1}{6} \sum_{i,j,k} v_3(ijk; \Omega) + \frac{1}{24} \sum_{i,j,k,l} v_4(ijkl; \Omega)$$

• Systematic approximations in GPT:

- neglect sp - d hybridization beyond E_{vol} and fold d -state non-orthogonality into v_2
- introduce canonical d bands:

$$\Delta_{dd'}(R_{ij}) \equiv \langle \phi_d | \Delta | \phi_{d'} \rangle = \alpha_m (R_{WS} / R_{ij})^5 \rightarrow \alpha_m (R_{WS} / R_{ij})^p$$

$p \sim 4-5$ $\alpha_0: \alpha_1: \alpha_2$
bcc metals 6: -4: 1

$$v_2(r) = v_2^{sp}(r) + v_2^{hc}(r) + \underline{v_a} [f(r)]^4 - \underline{v_b} [f(r)]^2$$

$$f(r) \equiv (1.8R_{WS} / r)^p$$

$$v_3(r_1, r_2, r_3) = \underline{v_c} f(r_1) f(r_2) f(r_3) L(\theta_1, \theta_2, \theta_3) + \underline{v_d} \{ [f(r_1) f(r_2)]^2 P(\theta_3) + [f(r_2) f(r_3)]^2 P(\theta_1) + [f(r_3) f(r_1)]^2 P(\theta_2) \}$$

L, P, M universal
angular functions
(d symmetry)

$$v_4(r_1, r_2, r_3, r_4, r_5, r_6) = \underline{v_e} [f(r_1) f(r_2) f(r_3) f(r_4) M(\theta_1, \theta_2, \theta_3, \theta_4, \theta_5, \theta_6) + f(r_3) f(r_2) f(r_6) f(r_5) M(\theta_7, \theta_8, \theta_9, \theta_{10}, \theta_5, \theta_{12}) + f(r_1) f(r_6) f(r_4) f(r_3) M(\theta_{11}, \theta_{12}, \theta_5, \theta_6, \theta_3, \theta_4)]$$

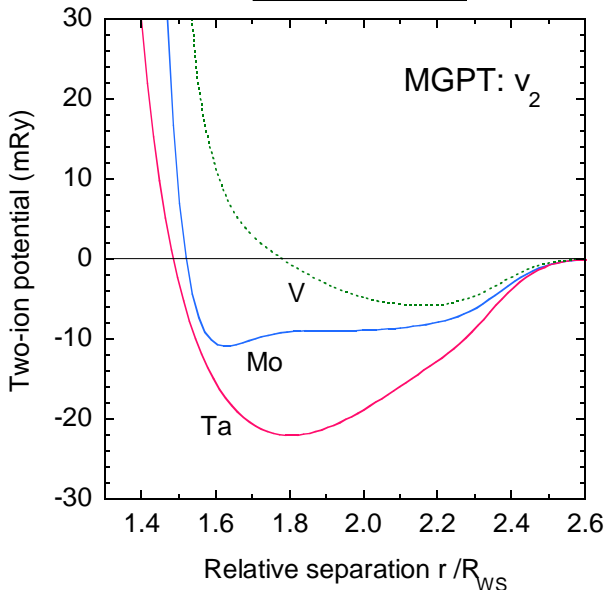
Advanced-generation MGPT potentials: Ta, Mo, V



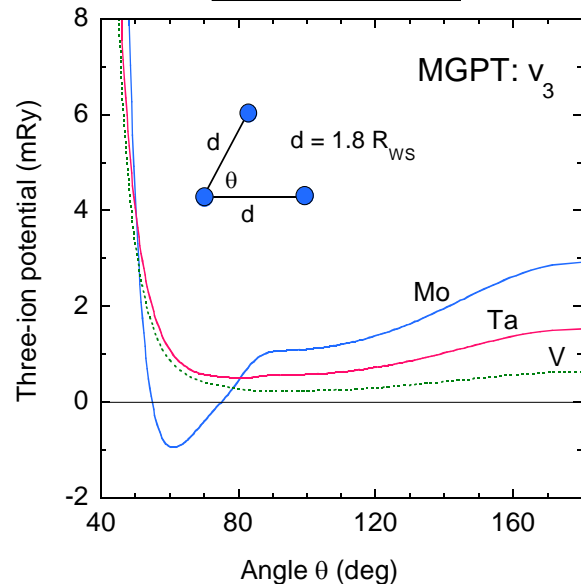
- **Parameter constraints:** bcc DFT and/or experimental data as a function of Ω

$-E_{vol}$: E_{coh} $-v_a$: C_{44} $-v_b$: E_{vac}^0 compressibility sum rule reduces
 $-v_d$: B $-v_e$: C' $-v_c$: Θ_D independent parameters to 5

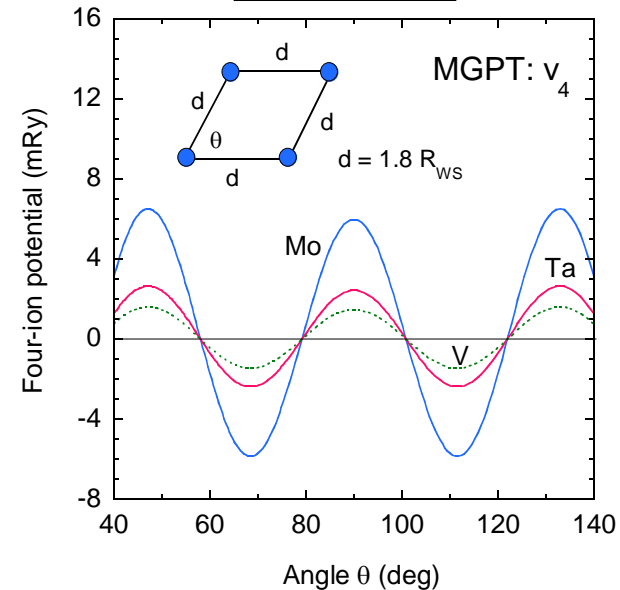
Two-ion



Three-ion



Four-ion

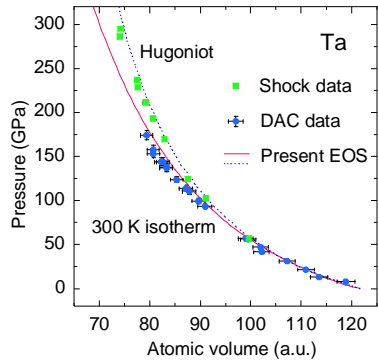


- **Pressure ranges treated:**

- Ta to 1000 GPa
- Mo to 400 GPa
- V to 230 GPa

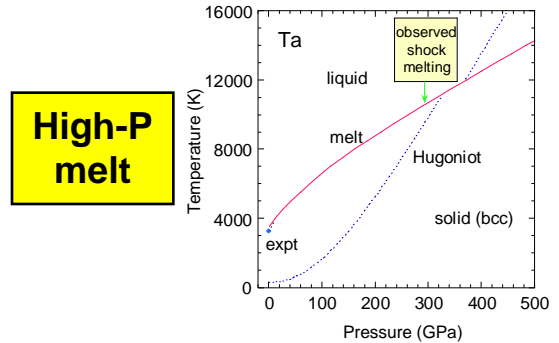
Volume-dependent MGPT potentials available over wide pressure ranges

Transition-metal MGPT potentials have been widely applied to thermodynamic and mechanical properties

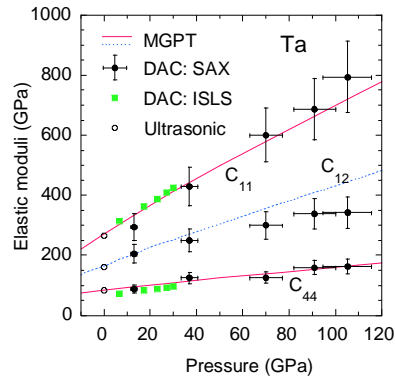


Multi-phase EOS

- Structural and thermo-dynamic properties:
 - phase transitions
 - phonons
 - high-pressure melting
 - multiphase EOS
 - rapid solidification
 - thermoelasticity

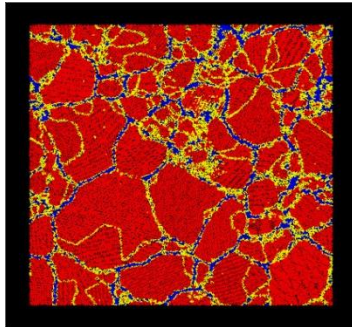


High-P melt

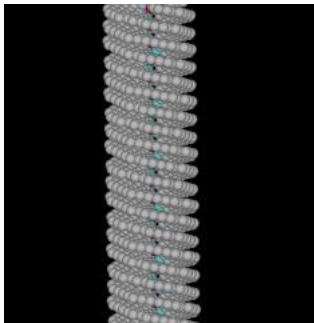


High-P,T elastic moduli

- Defects and mechanical properties:
 - high-pressure elastic moduli
 - vacancy, self-interstitial formation and migration
 - grain boundary structure
 - dislocation structure and mobility
 - multiscale modeling of plasticity and strength

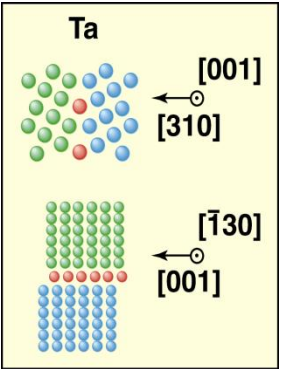


Rapid solidification



Dislocation structure and mobility

Grain boundary atomic structure



Structural phase stability and high-pressure phase transitions in central *d*-transition metals



• Primary trends

- structure controlled by ***d*-band filling**: hcp – bcc – hcp sequence
- *sp* → *d* electron transfer under pressure
- high-*P* transition to structure on immediate right:
 - IVB metals → bcc
 - VB metals remain stable in bcc
 - VIB metals → hcp

IVB	VB	VIB	VIIB
hcp Ti	bcc V	bcc Cr	hcp (Mn)
Zr	Nb	Mo	Tc
Hf	Ta	W	Re

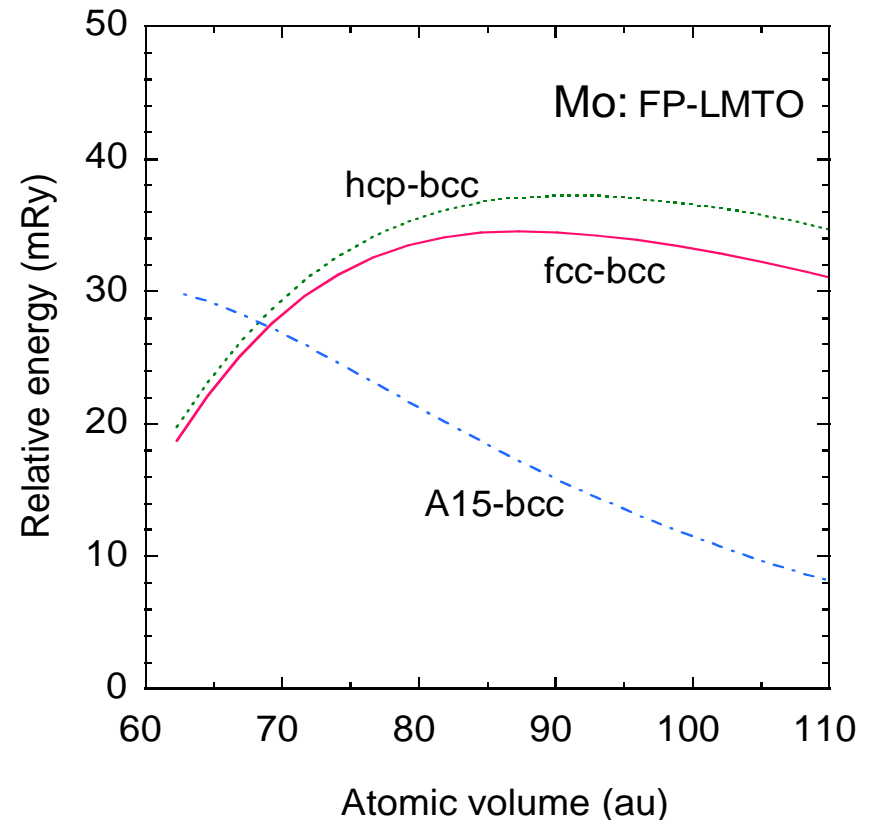
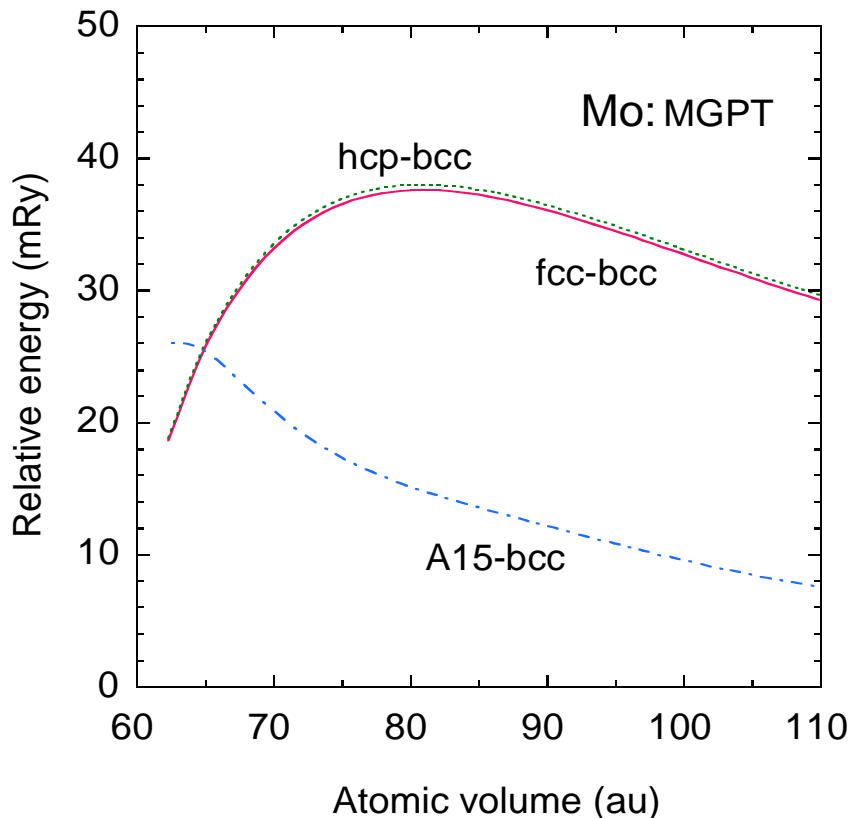
• Secondary trends

- driven by details of electronic structure
- IVB metals: intermediate ω phase, so high-*P* sequence is hcp → ω → bcc
- bcc metals: competitive A15 structure, especially in Ta and W at low *P*
possibly stable ω phase in Ta at high *P, T*
- VB metals: Fermi-surface driven elastic anomalies: bcc → rhom → bcc in V

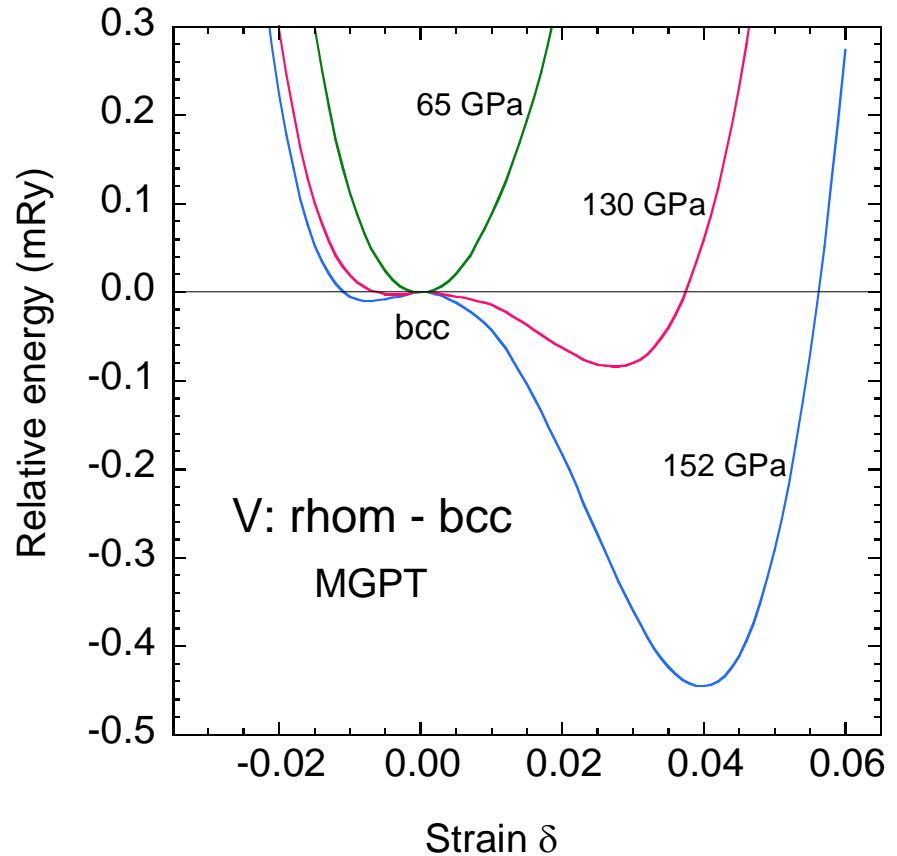
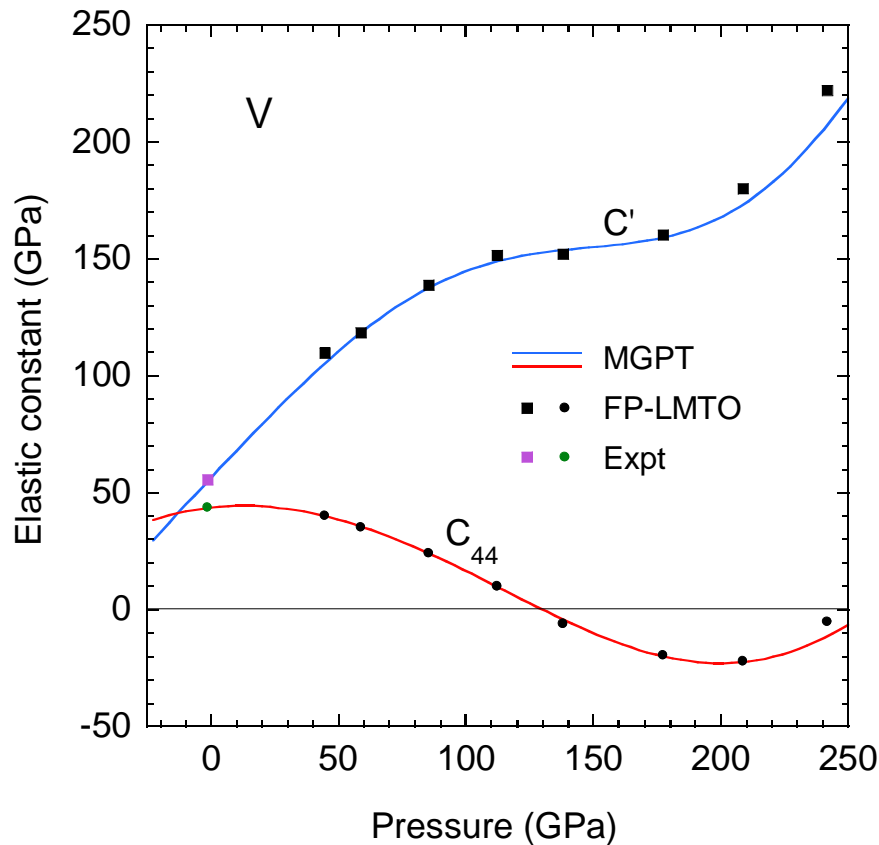
Structural phase stability in Mo



- **MGPT structural energies and high-pressure trends:**
 - good description **without constraint:** v_4 essential to correct physics
 - bcc \rightarrow hcp predicted beyond 400 GPa: sign of v_4 changes
 - systematic improvement possible: beyond canonical bands and/or beyond v_4



Elastic anomalies and bcc \rightarrow rhom transition in V



- **bcc \rightarrow rhom transition seen in DAC at 69 GPa:** Ding *et al.*, *PRL* **98**, 085502 (2007)
- **MGPT potentials capture this behavior through elastic moduli C_{ij} :**
 - softening of C_{44} is precursor to transition
 - transition onset near 65 GPa: $T_2[110]$ zone-boundary phonon becomes imaginary

Multiphase equation of state and melt: Ta prototype



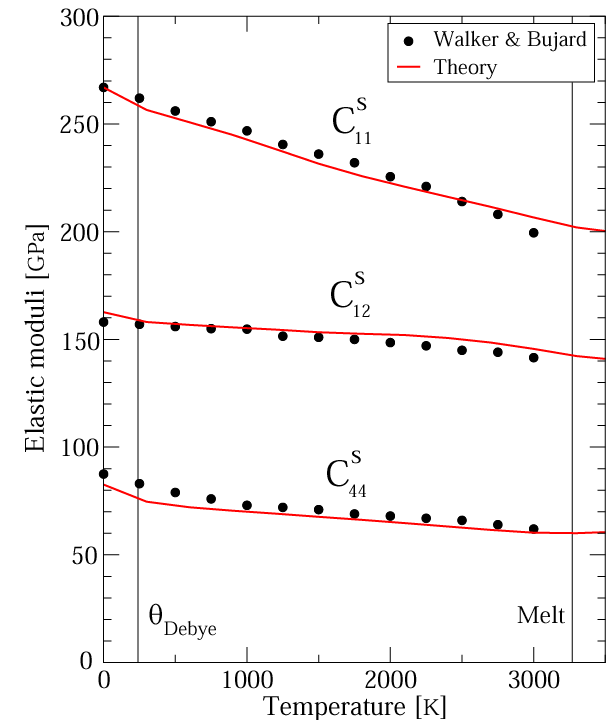
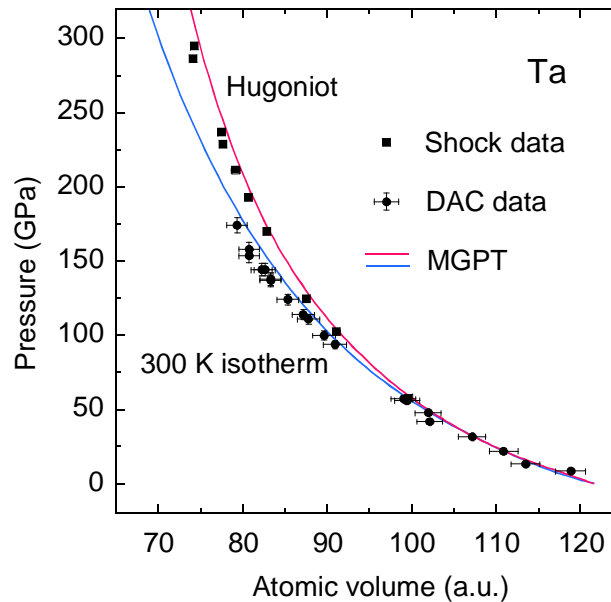
$$A^\alpha(\Omega, T) = E_0(\Omega) + A_{ion}^\alpha(\Omega, T) + A_{el}^\alpha(\Omega, T)$$

$\alpha = bcc, (A15, \omega, \dots), liquid$

free energy: cold ion-thermal electron-thermal

• Cold and electron-thermal components: FP-LMTO coupled to MGPT

- $T = 0$ properties:
 $E_0, P_0; C_{ij}, \dots$
constraints for
MGPT potentials
- finite temperature:
 $A_{el}, P_{el}, E_{el}, S_{el}$
high- T structure
from MD/MGPT

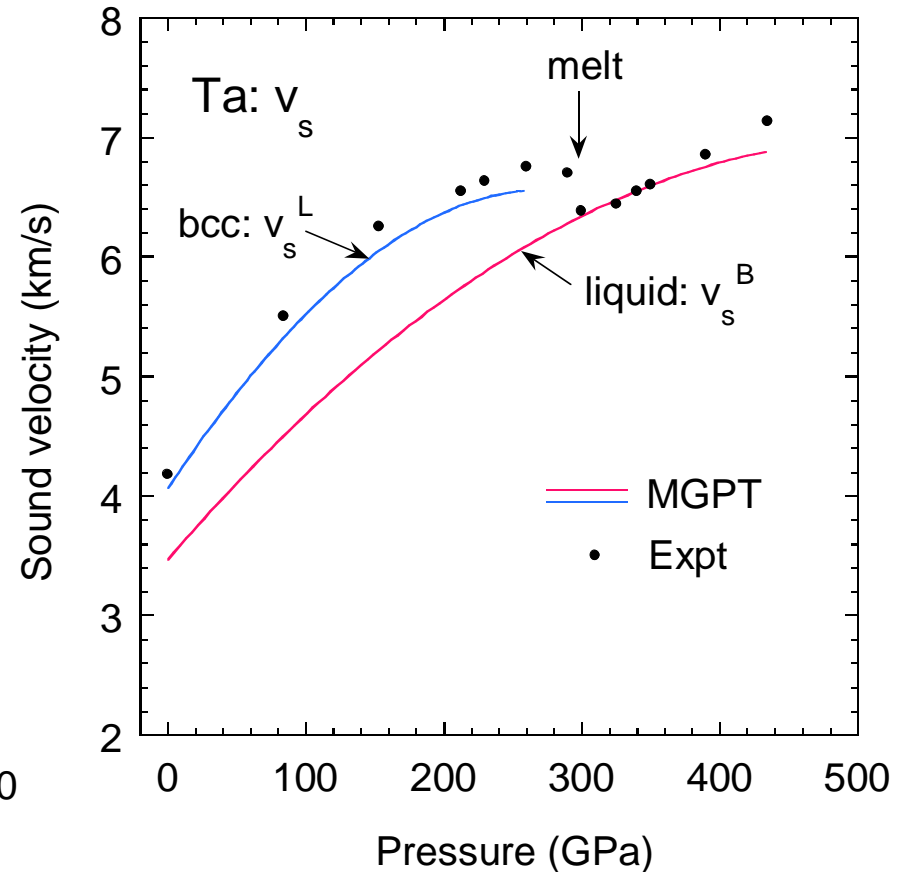
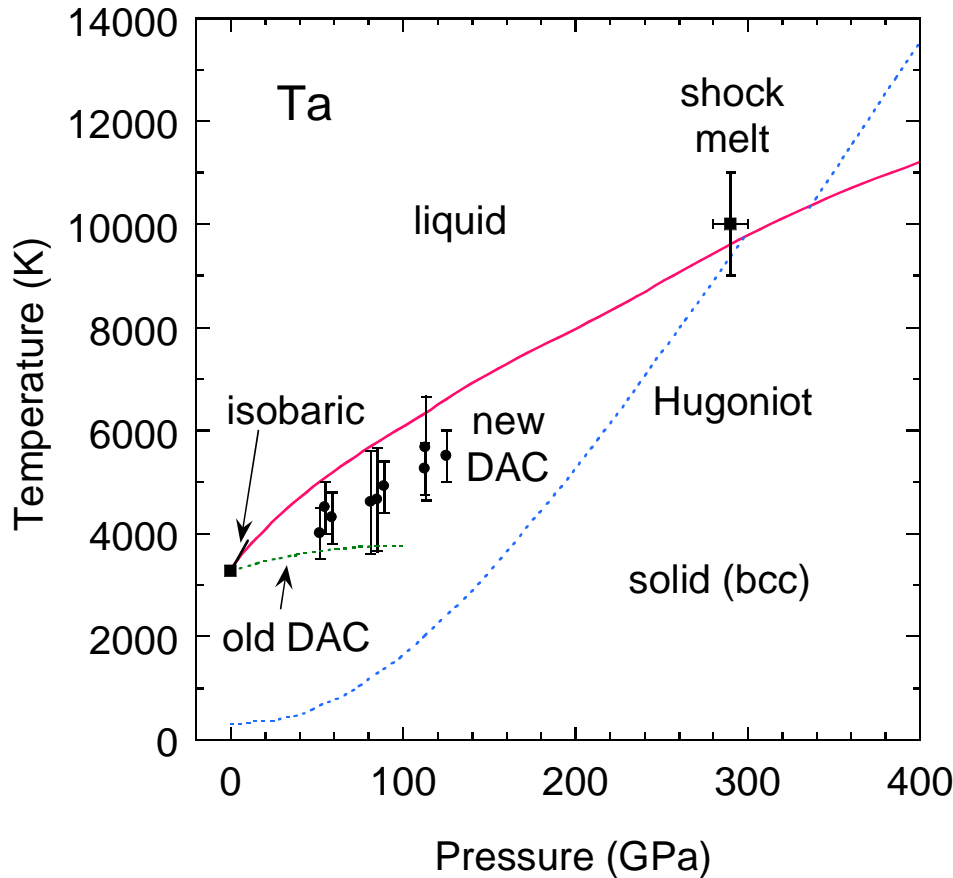


• Ion-thermal components: MGPT

- lattice/liquid thermal properties: $A_{ion}, P_{ion}, E_{ion}, S_{ion}$
- MD simulation in high- T solid and liquid

• Extension to *thermoelasticity*, and recently *polymorphism*, in high- P, T solid

High-pressure Ta melt curve and shock melting

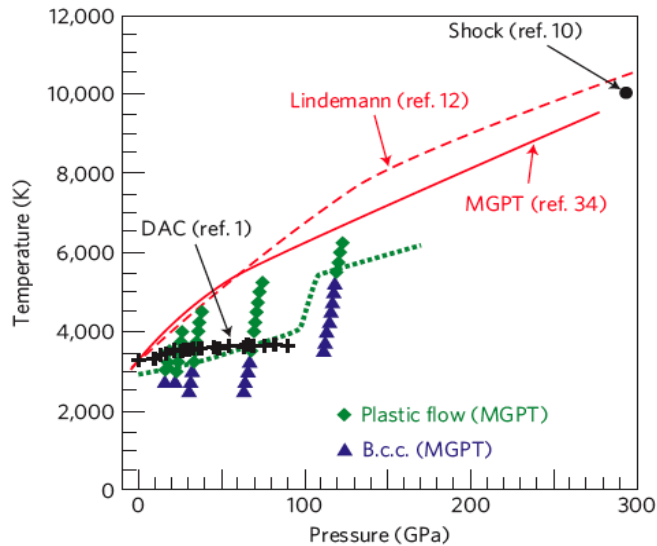


Predicted melt curve agrees with shock and isobaric data, and there is improved agreement with new DAC data: *PRL* 104, 255701 (2010)

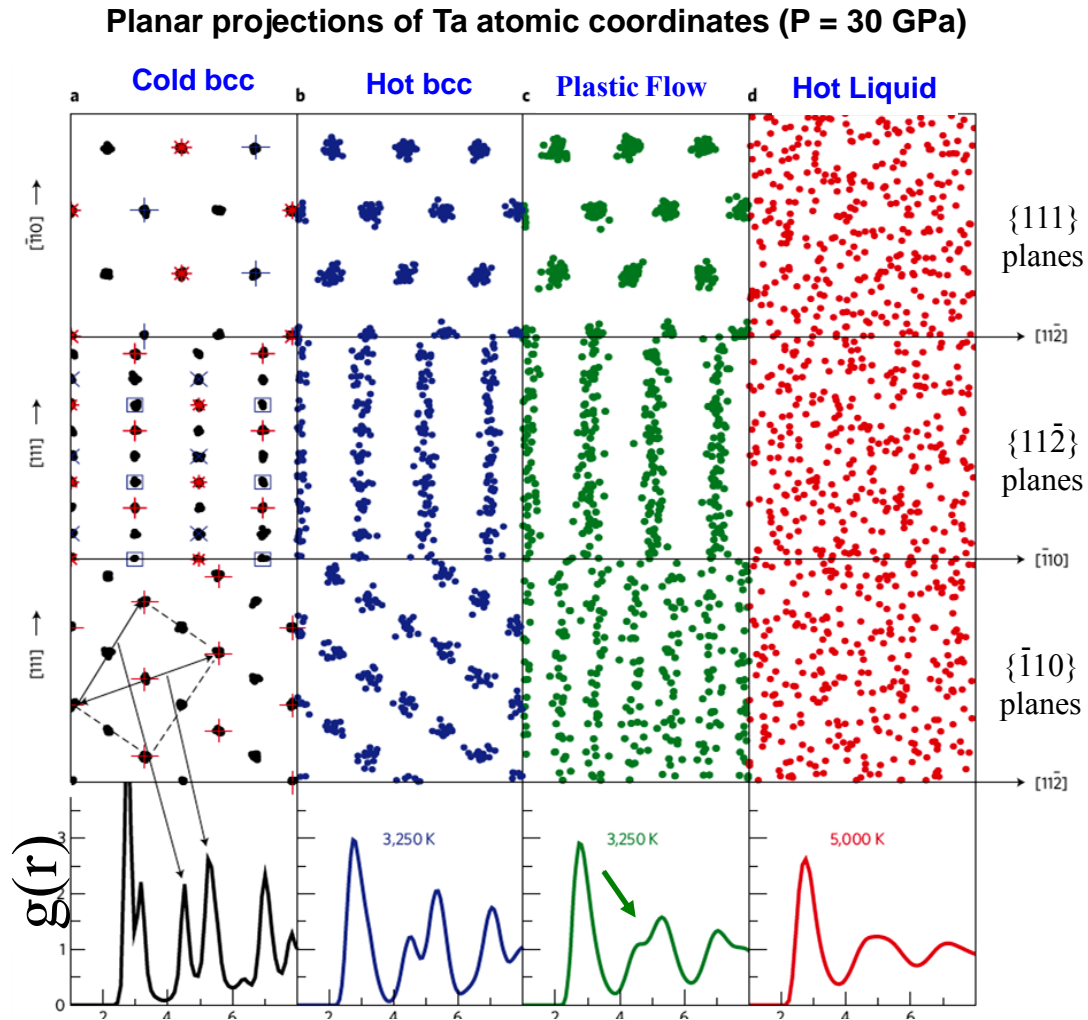
Structural disorder of bcc in Ta under shear loading



- MD/MGPT simulations of partial disorder of bcc structure at high T
- Dislocation-free plastic flow on $\{110\}$ planes matches original DAC “melt”



- Possible link to newly discovered polymorphism: Burakovsky *et al.*, *PRL* **104**, 255702 (2010)



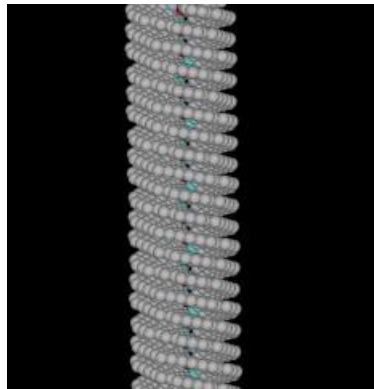
Wu *et al.*, *Nature Materials* **8**, 223 (2009)

Accurate atomistic simulations of dislocation properties in bcc transition metals

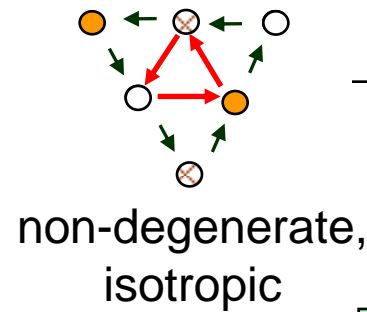


- Core structure and its pressure dependence

$a/2\langle 111 \rangle$
screw
dislocation

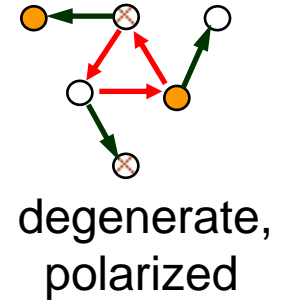


- Peierls stress τ_P and orientation dependence
- Kink and kink-pair energetics, including stress-dependent activation enthalpy $\Delta H(\tau)$
- Pressure scaling of τ_P and ΔH
- Dynamic simulations of structure and mobility



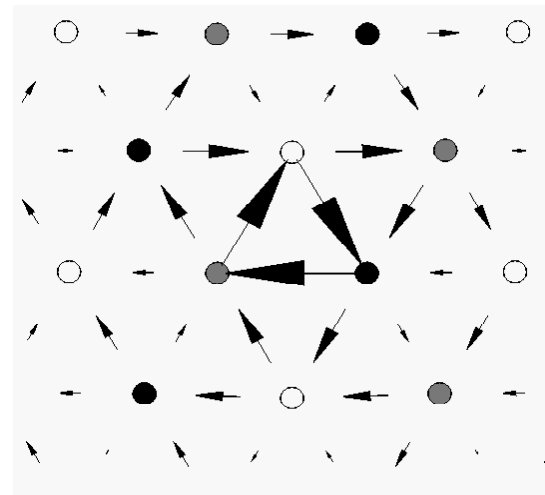
$P = 0$

P

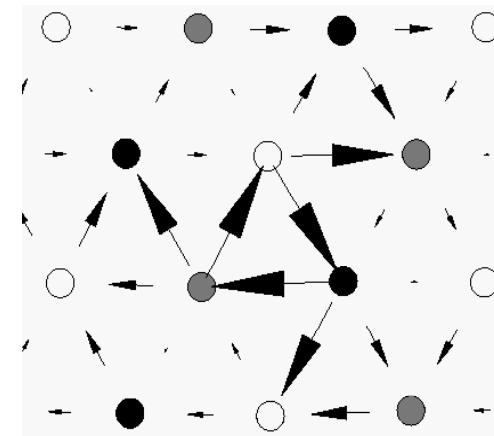


$P = 1000 \text{ GPa}$

bcc Ta



Current consensus view near ambient



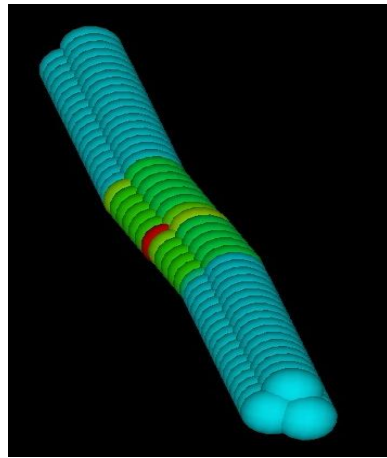
But... pressure sensitive core

Linking atomistics to microscale dislocation dynamics (DD) simulations



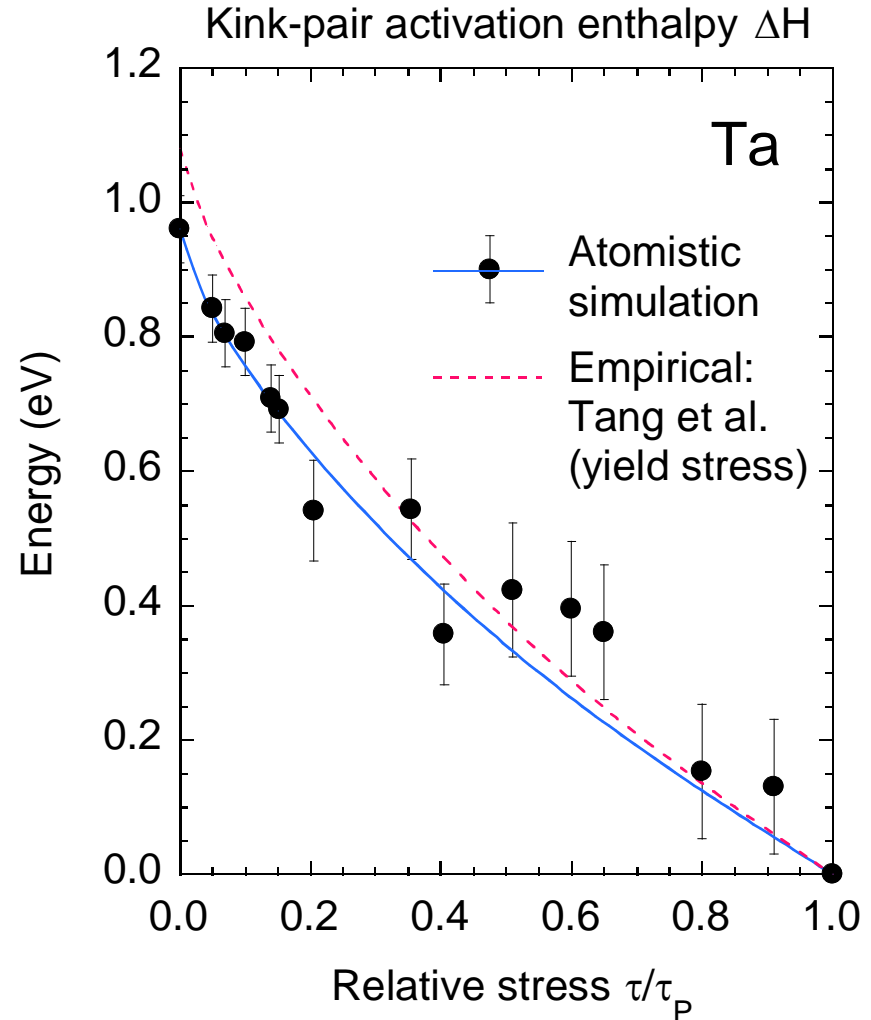
- Screw dislocations move via thermally activated kinks

Left kink of
 $a/2\langle 111 \rangle$
kink pair



$$v_{screw}(\tau) \propto \exp[-\Delta H(\tau) / k_B T]$$

- Stress-dependent activation enthalpy ΔH
 - controls **dislocation mobility** and is key input into DD simulations of yield stress
 - orientation dependence and **pressure scaling** through $\Delta H(0)$ and τ_p



Extended to high pressure for DD yield stress simulations

Atomistically informed DD simulations of single-crystal yield stress in bcc metals

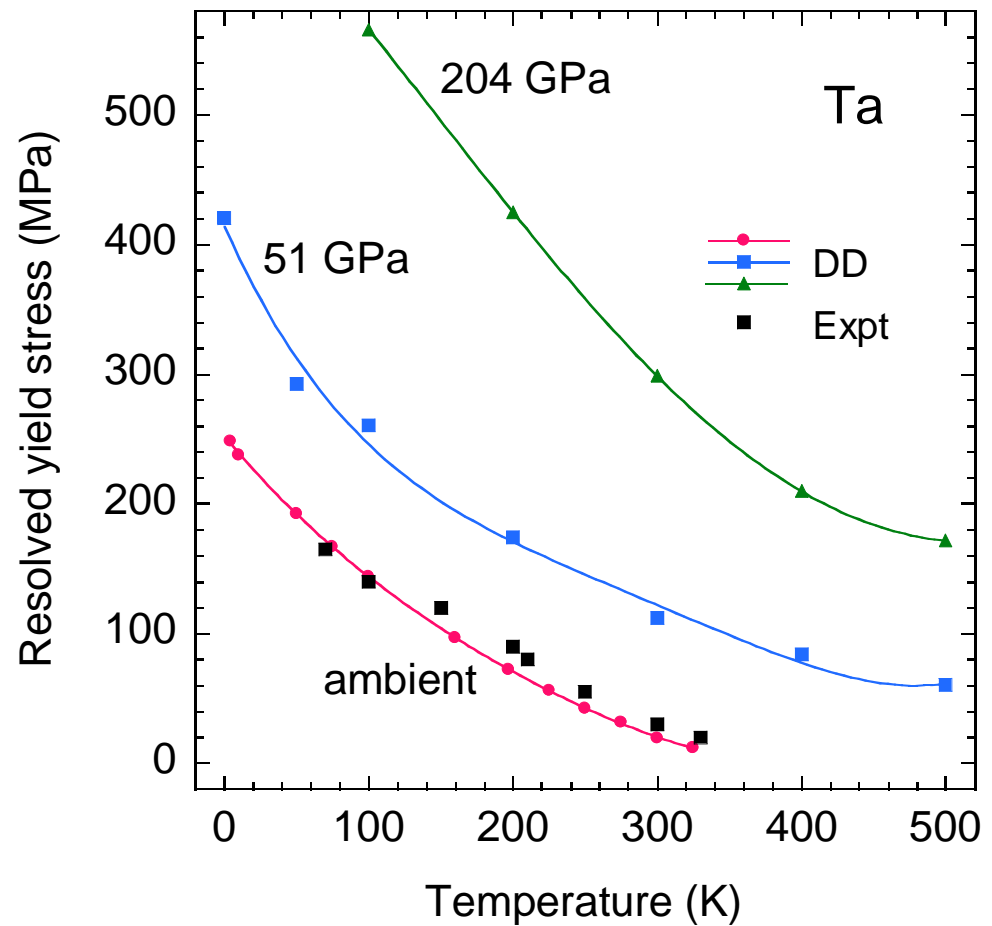


- Atomistic calculations of **kink-pair enthalpy** fitted to analytic form needed for DD:

$$\Delta H(\tau) = \Delta H(0)[1 - (\tau / \tau_P)^p]^q$$

for each pressure considered

- Additional needed quantities τ_P , ν_D , b etc. are also imported from atomistic calculations
- In Ta, τ_P is *scaled down* by about a factor of two to account for ambient-pressure overestimate
- Similar DD simulations have also been done for Mo, but *without* the need for τ_P scaling



Matrix MGPT for f electrons, non-canonical bands and high speed



- On-the-fly matrix multiplication of angular functions P, L, M :

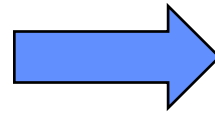
$$P \propto \text{Tr}(\hat{H}_{ij}\hat{H}_{ji}\hat{H}_{ik}\hat{H}_{ki})$$

$$L \propto \text{Tr}(\hat{H}_{ij}\hat{H}_{jk}\hat{H}_{ki})$$

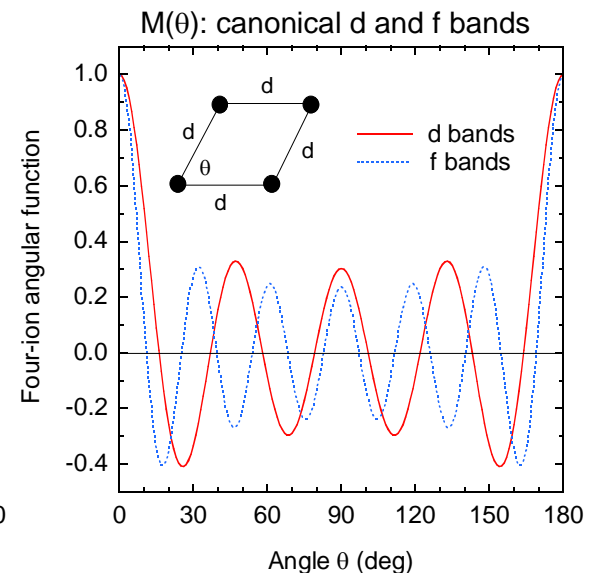
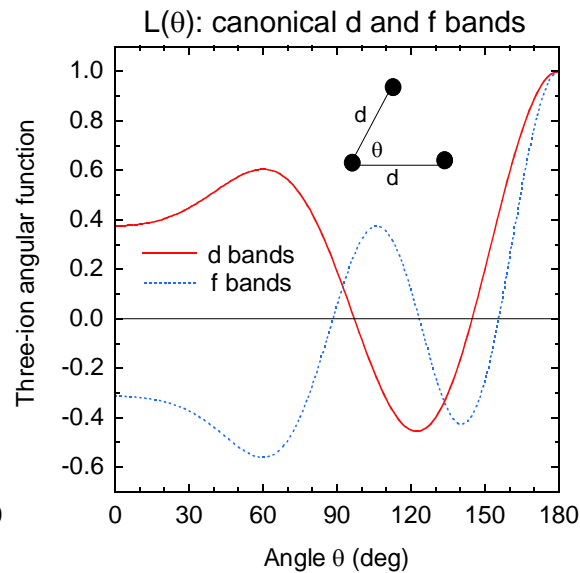
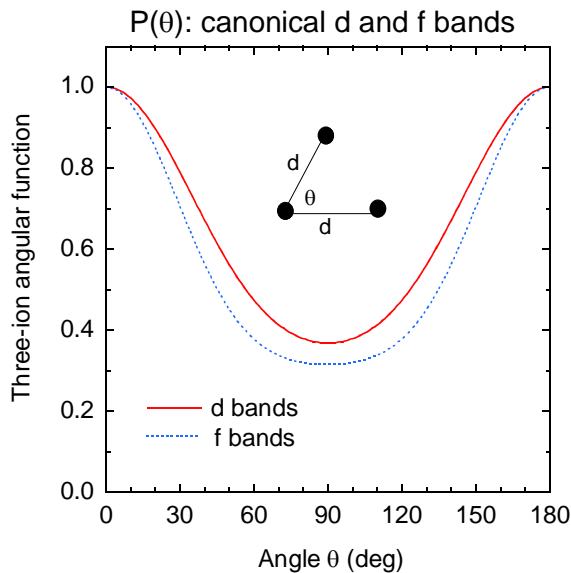
$$M \propto \text{Tr}(\hat{H}_{ij}\hat{H}_{jk}\hat{H}_{kl}\hat{H}_{li})$$

- Canonical bands: $d \rightarrow f$ extension for actinide metals

$$\begin{array}{l} d \text{ states: } \ell = 2 \quad \alpha_0: \alpha_1: \alpha_2 \\ p = 2\ell + 1 = 5 \quad 6: -4: 1 \end{array}$$



$$\begin{array}{l} f \text{ states: } \ell = 3 \quad \alpha_0: \alpha_1: \alpha_2: \alpha_3 \\ p = 2\ell + 1 = 7 \quad 20: -15: 6: -1 \end{array}$$



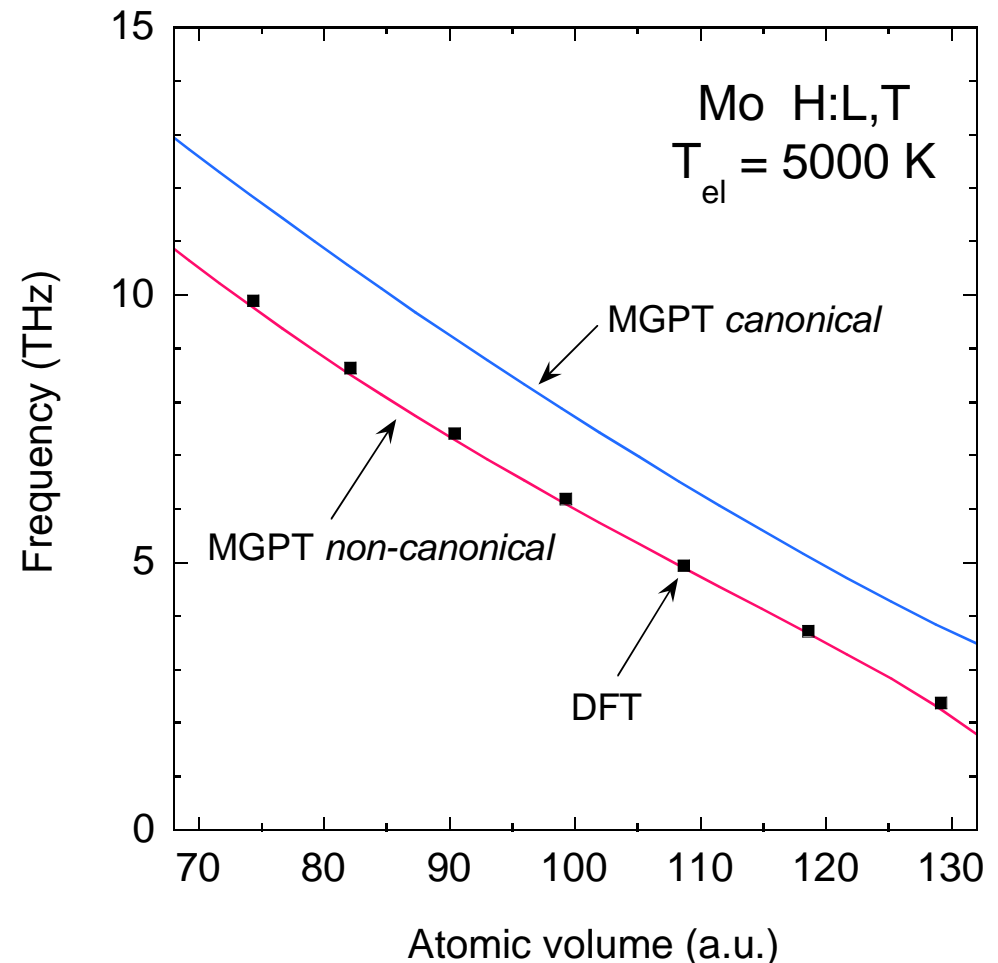
- Non-canonical bands: p and α_m become variable input parameters
- Fast algorithms: analytic forces with 10-fold speed increase over standard MGPT

Non-canonical bands for improved accuracy



- Non-canonical bands permit an improved description of the underlying electronic structure at **no additional computational cost**
- For d bands, there are two additional MGPT parameters:
$$c_0 = \alpha_0 / \alpha_2 \quad c_1 = \alpha_1 / \alpha_2$$
which can be volume dependent
- For a given electron temperature a single set of parameters c_0, c_1 improve **all phonons frequencies** at **all volumes**

H-point bcc phonon:



Inclusion of $sp-d$ hybridization in MGPT formalism is important for series-end transition metals



In full GPT: $v_2 = v_2^{hc} + v_2^{sp} + v_2^{sp-d} + v_2^d$

$$v_3 = v_3^{sp-d} + v_3^d$$

$$v_4 = v_4^{sp-d} + v_4^d$$

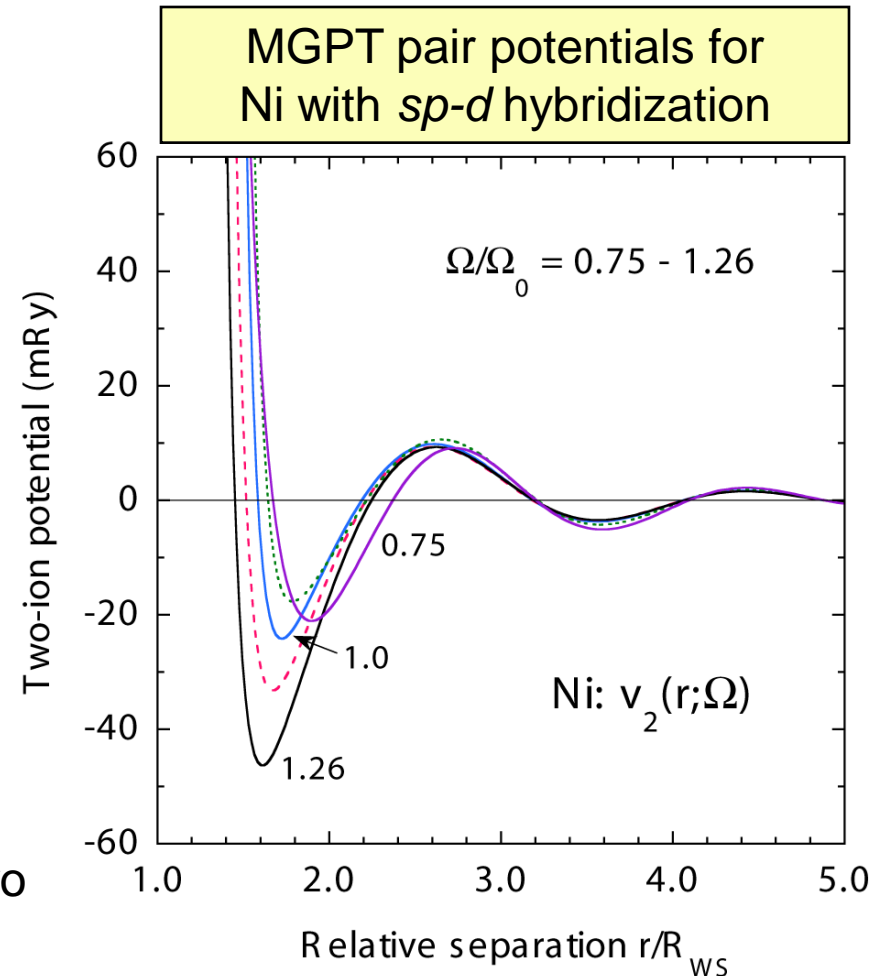
In MGPT:

- model v_n^d via *canonical* or *non-canonical* d bands in usual way
- introduce screened effective hybridization potential:

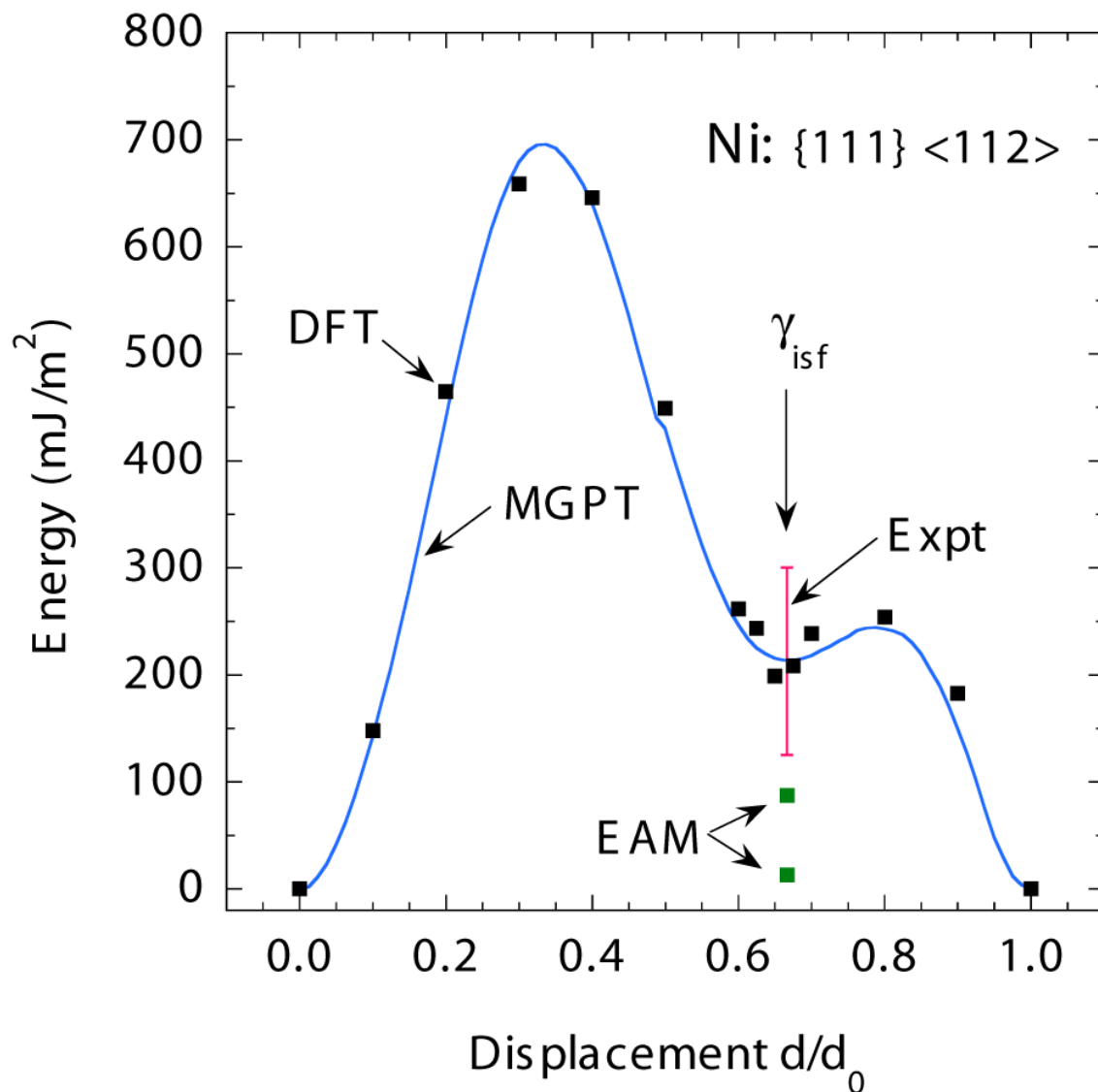
$$v_{2-eff}^{sp-d} = v_2^{sp-d} + \langle v_3^{sp-d} \rangle + \langle v_4^{sp-d} \rangle + \dots$$

$$= v_2^{sp-d} f_{scr}$$

- potential range reduced by factor of two
- successfully applied to Ni at v_2 level



Ni generalized stacking fault (GSF) energies at ambient pressure



- MGPT closely matches DFT over the entire $\{111\}\langle 112\rangle$ boundary
- Intrinsic stacking fault energy γ_{isf} calculated in experimental range
- In contrast, short-range EAM potentials underestimate γ_{isf}
- Ni MD/MGPT simulations of dynamic fracture in progress

Temperature-dependent MGPT potentials for strong-coupling transition metals: Mo prototype



- Use free-energy functional at finite *electron temperature*: $T_{el} = T_{ion} = T$

$$A_{tot}(R_1, \dots, R_N) = NA_{vol}(\Omega, T) + \frac{1}{2} \sum_{i,j} v_2(ij; \Omega, T) + \frac{1}{6} \sum_{i,j,k} v_3(ijk; \Omega, T) + \frac{1}{24} \sum_{i,j,k,l} v_4(ijkl; \Omega, T)$$

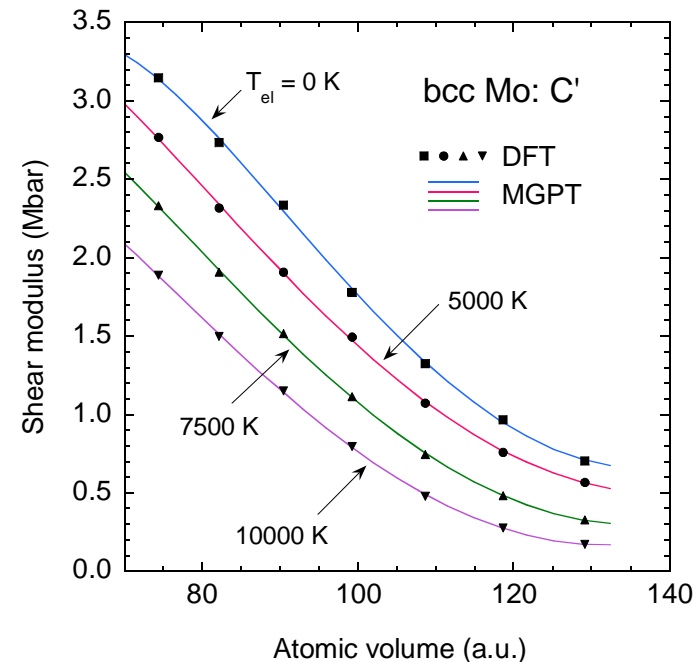
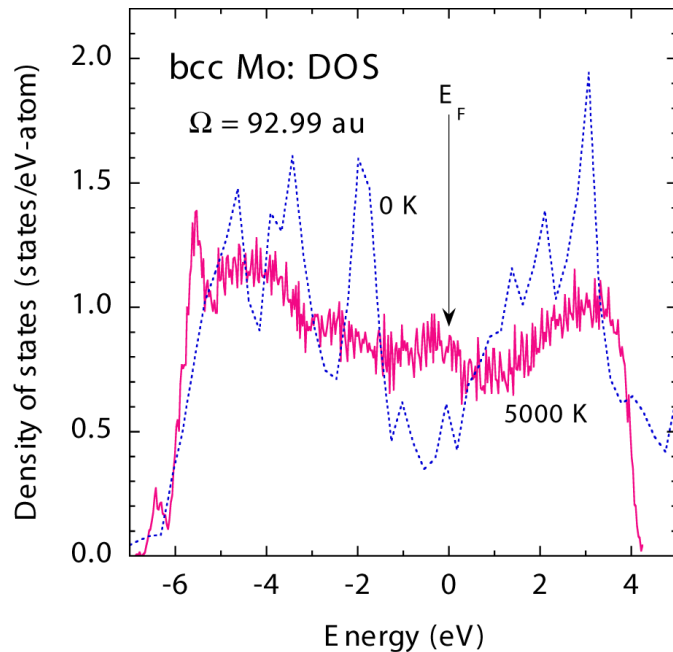
volume

radial forces

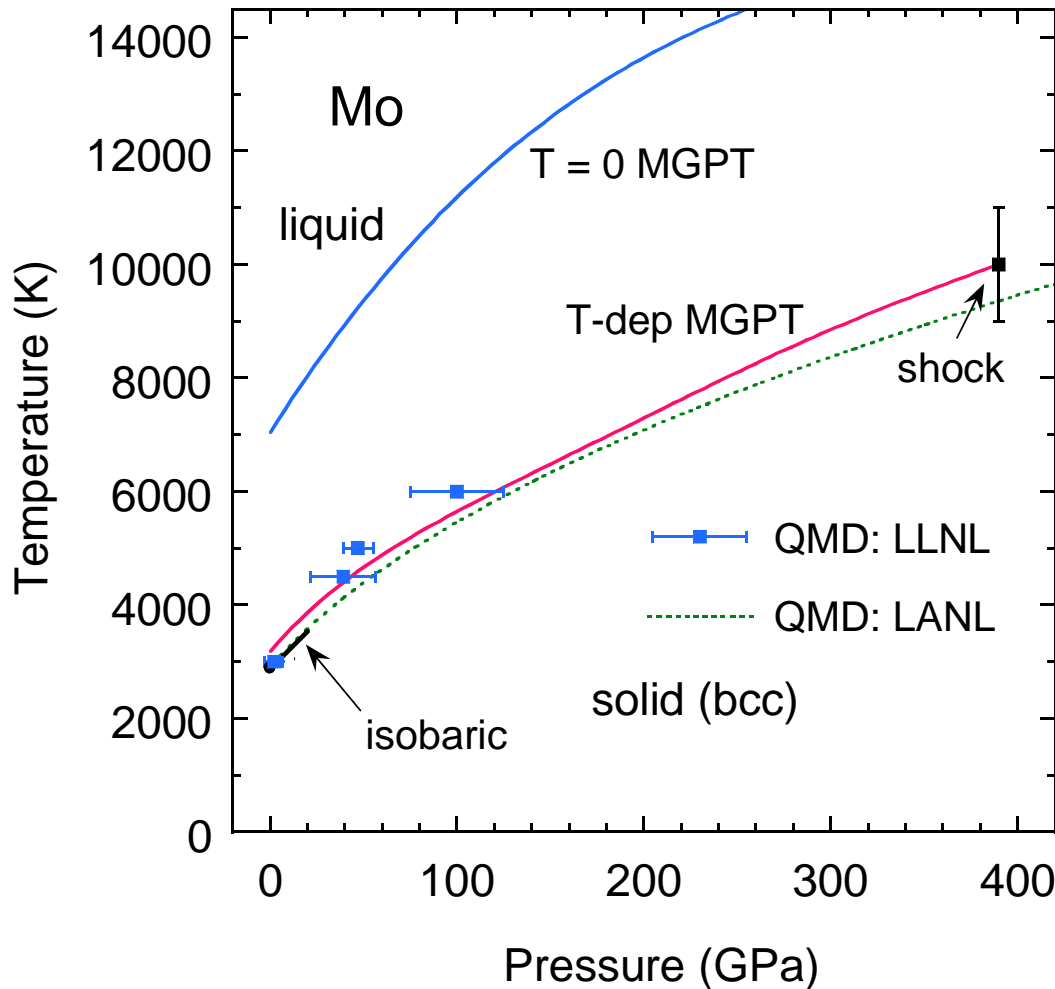
angular forces

– subsumes electron thermal A_{el} and provides T -dependent forces for MD

- Density of states (DOS), structural and elastic properties sensitive to T_{el}



Melting in Mo requires temperature-dependent MGPT potentials



- $T = 0$ MGPT potentials overestimate melt T_m by factor of two
- T -dep MGPT melt in good agreement with isobaric and shock data as well as with first-principles QMD simulations
- Polymorphism in high- P, T solid currently being studied with T -dependent potentials